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(54) **IMPLANT DEVICE**

(57) An implantable device including a metal substrate ;that contains particles having a size of 1 μm or more; if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μm and the average content of the particles is less than or equal to 40 ppm; if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal

to 0.2 mm, the largest particle size is less than or equal to 20 μm and the average content of the particles is less than or equal to 100 ppm; The size of the particles and the average content of the particles are reasonably controlled according to the wall thickness of the metal substrate, improving the plastic deformation capability of the implantable device.

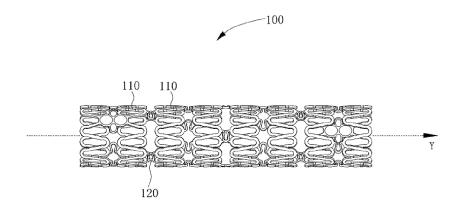


Fig. 1

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Field

[0001] The embodiments relate to the field of interventional medical devices, and in particular to an implantable device.

Background

[0002] As a kind of meshed/tubular implantable medical device, the intravascular stent can be used in the treatment of various vascular diseases. An intravascular stent is implanted into a lesion segment to support the stenosed and occluded blood vessels, thus reducing the elastic retraction and reshaping of the blood vessels, while maintaining a smooth lumen blood flow.

[0003] Intravascular stents are generally made from metal or high polymer materials. An intravascular stent is generally cut or braided into a desired shape, and then crimped to a delivery balloon or a delivery sheath to be fixed in a delivery system; during such process, the stent may reduce 50% above in its outer diameter and experiences large deformation. The intravascular stent is released and expanded after being delivered to the lesion; during such process, the intravascular stent is expanded 200% above in its outer diameter again and experiences larger deformation. The intravascular stent undergoes repeated large deformations during the crimping and expansion process. Moreover, the stent will be buckled, stretched, and even twisted along with the movement, contraction, and relaxation of blood vessels after being implanted in the body; that is, the stent bears periodic loads (such as radial pulsation squeezing, axial tension and buckling) in blood vessels, which demands for high plastic deformation capacity of the stent. However, the existing stent lacks sufficient plastic deformation capacity, resulting in fracture due to fatigue after implantation, and even fracture during expansion. The fracture will cause undesirable consequences: on the one hand, the fractured stent strut will cause local mechanical vascular stimulation, resulting in inflammation and neointimal hyperplasia; on the other hand, the fractured stent strut will damage the local stent structure, resulting in thrombosis and blood flow blockage, thereby affecting the blood flow supply of organs. The above undesirable consequences may not only cause the loss of the radial support performance of the local stent region, thus making it difficult to play the role of radial support, but also may bring great clinical risks to the patient.

[0004] The plastic deformation capacity of the intravascular stent is mainly related to its structural design and stent material; and when the structural design of the stent is determined, the plastic deformation capacity of the material itself will play a greater role. The plastic deformation capacity of a metal-substrate material depends on its microstructure which includes grain size and orientation, metallographic structure, second phase parti-

cles, dislocation structure and the like. The plastic deformation capacity greatly varies from different microstructures, and thus can be optimized by optimizing the microstructure.

Summary

[0005] In view of this, it is necessary to provide an implantable device having good plastic deformation capacity.

[0006] Embodiments include an implantable device, including a metal substrate containing particles having a size of 1 μ m above, where:

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m and the average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to $20~\mu m$ and the average content of the particles is less than or equal to 100~ppm;

and if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m and the average content of the particles is less than or equal to 220 ppm.

[0007] In one embodiment, if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m and the average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μ m and the average content of the particles is less than or equal to 100 ppm;

and if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μm and the average content of the particles is less than or equal to 220 ppm.

[0008] In one embodiment, if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m and the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the

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largest size of the particles is less than or equal to 15 μ m and the average content of the particles is less than or equal to 50 ppm;

and if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μ m and the average content of the particles is less than or equal to 110 ppm.

[0009] In one embodiment, if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 50 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 100 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 110 ppm;

and if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 220 ppm.

[0010] In one embodiment, if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 25 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 50 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

[0011] In one embodiment, if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to

0.12 mm, the largest size of the particles is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 25 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 50 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

[0012] In one embodiment, the material of the metal substrate could be nitrided iron, pure iron, cobalt-chromium alloys and magnesium alloys.

[0013] In one embodiment, the implantable device could be an intravascular stent, a biliary stent, an esophageal stent, or a urethral stent.

[0014] In one embodiment, the intravascular stent could be a coronary stent or a peripheral vascular stent. [0015] In one embodiment, the metal substrate material is prepared by electroslag remelting and then vacuum arc melting.

[0016] Experiments related to the embodiments prove that reasonable control of the size and the average content of the particles according to the wall thickness of the metal substrate of the implant device can optimize the microstructure of the metal substrate, which is beneficial to the improvement in the plastic deformation capacity of the implantable device, thus reducing the risk of abnormal fracture of the implantable device.

Brief Description of the Drawings

[0017]

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Fig. 1 is a structure diagram of a metal substrate of an implantable device in one embodiment;

Fig. 2 is a schematic diagram showing the axial expansion of the metal substrate of the implantable device shown in Fig. 1;

Fig. 3 is a scanning electron microscope (SEM) image showing a fracture of a coronary stent in Example 2;

Fig. 4 is an SEM image showing a fracture of a coronary stent in Comparative Example 1; and

Fig. 5 is an SEM image showing a fracture of a coronary stent in Comparative Example 2.

Detailed Description of the Embodiments

[0018] For the convenience of understanding, the embodiments will be described more comprehensively with reference to the accompanying drawings. Embodiments are shown in the accompanying drawings. The embodiments may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are exemplary and non-limiting.

[0019] Unless defined otherwise, all terms used herein have the same meanings as commonly understood by a person of ordinary skill in the art to which the embodiments belong. The terms used in the description of the embodiments herein are for the purpose of describing particular embodiments merely and are not limiting. As used herein, the term "and/or" includes any and all combinations of one or more of the associated items listed.

[0020] The particle size referred to herein is the maximum distance of two points on the edge of the particles within the same plane.

[0021] An implantable device in one embodiment is an intravascular stent, a biliary stent, an esophageal stent, or a urethral stent. In one embodiment, the intravascular stent is a coronary stent or a peripheral vascular stent.

[0022] As shown in Fig. 1, the implantable device includes a metal substrate 100; and the metal substrate 100 is a hollowed-out lumen structure.

[0023] Referring to Fig. 2 together, the metal substrate 100 includes a plurality of wave rings 110 arranged in an axial direction Y and connecting members 120 connecting two adjacent wave rings 110. Each wave ring 110 includes a plurality of waveform structures 112 arranged in a circumferential direction Z.

[0024] The metal substrate 100 is made of a metal material. In one embodiment, the material of the metal substrate 100 is one of nitrided iron, pure iron, cobalt-chro-

mium alloys, and magnesium alloys. It can be appreciated that in other embodiments, the metal substrate 100 may be made of other metals or alloys beyond those listed above; and any metal or alloy capable of satisfying the requirements of the implantable device and biocompatible with organisms well may be used.

[0025] The material for forming the metal substrate 100 contains a plurality of particles, resulting in the formation of a plurality of particles within the metal substrate 100; and the particle size is greater than or equal to 1 $\mu\text{m}.$ The particles include inclusions introduced externally, endogenous inclusions or a secondary phase as well. The particles may be from foreign substances introduced in the smelting process of a metal material. For example, a desoxidant is added to in a steel material to produce oxides and silicates during smelting; and sulfides and nitrides are formed in the solidification process of steel due to the decrease of the solubility of certain elements (such as sulfur and nitrogen); and these particles cannot be discharged in time and remain in the steel. It is difficult to achieve complete avoidance of particles, and at the same time, due to the random distribution, it is difficult to accurately control the distribution of these particles.

[0026] The size and content of the particles may adversely affect the microstructure of the metal substrate 100, thereby deteriorating the plastic deformation capacity of the metal substrate 100 to some extent. The extent of the deterioration mainly depends on the distribution and the size of the particles. The distribution of the particles in the severely deformed region of the metal substrate 100 is more likely to cause abnormal fracture of the implantable device. The larger the size of the particles is, the more serious the damage to the material continuity is; accordingly, it is more likely to cause the abnormal fracture of the implantable device. Thus, the particles can be controlled to reduce the risk of fracture of the implantable device. Therefore, it is necessary to reduce the amount of the particles, since the lower the amount of the particles is, the smaller the distribution probability of the particles in the deformation regions of the implantable device is; accordingly, it is less harmful.

[0027] The smaller the size of the particles is, the lower the damage to the material continuity is; and accordingly, it is less harmful. Moreover, the smaller the size of the implantable device is, the smaller the size of the particles should be, especially in the field of intravascular stents. At present, the thin-walled design may be preferred; and moreover, it may be more necessary to control the size of the particles when the wall thickness is thinner. It has been found that when the size of the particles in metalbased materials is less than 1 µm, these sub-micron or nano particles have little effect on the plastic deformation capacity of the material, and even can enhance the plastic deformation capacity to improve the strength of the material. But when the size of the particles is 1 μm or more, the particles will break the continuity of the material, possibly resulting in a decrease in the plasticity, toughness, and fatigue properties of the material. If these

particles are present in the deformation sites of the metal substrate 100, it is rather likely to cause abnormal fracture (e.g., fracture during expansion) of the metal substrate 100 at these sites. Therefore, it is necessary to control the size and content of particles having a size of 1 μm or more

[0028] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μ m and the average content of the particles is less than or equal to 40 ppm.

[0029] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 20 μ m and the average content of the particles is less than or equal to 100 ppm.

[0030] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 25 μ m and the average content of the particles is less than or equal to 220 ppm.

[0031] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 10 μ m and the average content of the particles is less than or equal to 40 ppm.

[0032] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 15 μm and the average content of the particles is less than or equal to 100 ppm.

[0033] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 20 μm and the average content of the particles is less than or equal to 220 ppm.

[0034] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 10 μ m and the average content of the particles is less than or equal to 20 ppm.

[0035] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 15 μ m and the average content of the particles is less than or equal to 50 ppm.

[0036] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 20 μ m and the average content of the particles is less than or equal to 110 ppm.

[0037] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 20 ppm.

[0038] If the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 40 ppm.

[0039] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 50 ppm.

[0040] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 20 μm; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 100 ppm. [0041] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 25 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 110 ppm. [0042] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 25 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 220 ppm.

[0043] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm.

[0044] If the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 20 ppm.

[0045] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 25 ppm.

[0046] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average

content of the particles is less than or equal to 50 ppm. **[0047]** If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 25 μm ; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm. **[0048]** If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 25 μm ; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

[0049] In one embodiment, if the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm.

[0050] If the wall thickness of the metal substrate 100 is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest particle size is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 20 ppm.

[0051] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 25 ppm.

[0052] If the wall thickness of the metal substrate 100 is greater than 0.12 mm and less than or equal to 0.2 mm, the largest particle size is less than or equal to 15 μm; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 50 ppm. [0053] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm. [0054] If the wall thickness of the metal substrate 100 is greater than 0.2 mm and less than or equal to 0.3 mm, the largest particle size is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate 100 is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

[0055] N is defined as the theoretical over-expansion capacity of the metal substrate 100; L is defined as the length of a wave ring 110 of the metal substrate 100 after being straightened completely; and D is defined as the nominal outside diameter of the metal substrate 100,

$$N = \frac{L}{\pi} \cdot D \times 100\%$$

; where the nominal outside diameter is the nominal diameter of the metal substrate 100 plus double wall thickness. The nominal diameter refers to the inner diameter (the inner diameter of the metal substrate 100 after implantation in a blood vessel and expansion) of the metal substrate 100 after expansion. The nominal diameter is expressed in stent specifications terminology, for example, a 30008 stent, the nominal diameter is 3 mm and the nominal length is 8 mm after expansion; a 27538 stent, the nominal diameter is 2.75 mm and the nominal length is 38 mm after expansion; a 35015 stent, the nominal diameter is 3.5 mm and the nominal length is 15 mm after expansion.

[0056] The average content of the particles in the metal substrate 100 is the area occupied by the particles in per unit area of the metal substrate 100. That is, the average content of the particles in the metal substrate 100 is equal to the area occupied by the particles in a detection zone/the area of the detection zone; where the area of the detection zone is the total area of the detection zone; and the area occupied by the particles in the detection zone refers to the area occupied by the particles in a detection zone having a detection area of 10 mm² above randomly detected by an SEM at 500 magnifications. At least two detection zones are provided and are respectively distributed on two mutually perpendicular planes of the metal substrate 100; and the detection area on each detection zone is 5 mm² or more; that is, the average content of the particles is equal to the total area occupied by the particles in a plurality of detection zones/the total area of the plurality of detection zones.

[0057] The greater the size of the particles is, the higher the number of the particles is, and the larger the area of the particles on the metal substrate 100 per unit area is. When the average content of the particles is constant, the amount of the particles is less if the particle size is larger, so that the probability of the particles present in the critical deformation sites is small and its deterioration to the plastic deformation of the implantable device is weak. However, when the average content of the particles is constant, the particle size is small if the amount of the particles is higher; even though the particles are present in the critical deformation sites, the deterioration to the plastic deformation of the implantable device is weak. Therefore, the size and the content of the particles are reasonably controlled, so as to avoid the adverse effects of the particles on the plastic deformation capacity of the implantable device.

[0058] In one embodiment, the material of the metal substrate 100 is prepared by at least one of electroslag remelting and vacuum arc melting. Particles of the metal substrate 100 is mainly from raw materials thereof; and the level (size and average content) of the particles is not substantially affected during the preparation of the metal substrate 100. Therefore, there is a need to control

the level of the particles in the raw material. Electroslag remelting and vacuum arc melting can improve the purity of the metal material, reduce the level of the particles in the metal material, and can optimize the microstructure of the metal material, thereby optimizing the plastic deformation capacity of the metal material.

[0059] Electroslag remelting is a process that an electrode is molten by resistance heat generated by electric current through molten slag as a heat source, and then the molten metal is gathered drops into a metallic bath after through a slag layer; during passing through the slag layer, nonmetallic inclusions are absorbed by the slag, and harmful elements (phosphorus, sulfur, lead, stibium, bismuth, tin and the like) are effectively removed through steel-slag reaction and high-temperature vaporization, so that the steel ingots are purified and finally solidified into castings in a water cooled crystallizer.

[0060] Vacuum arc melting refers to a smelting process that a material to be smelted serves as an electrode and a water-cooled copper crucible serves as another electrode, and then arc strike is conducted between the two electrodes; and then the material to be smelted is molten by high temperature of the arc, dropping in the crucible, then gradually molten and condensed into an ingot. Vacuum melting can significantly remove hydrogen and other volatile impurities and can obviously reduce the content of the particles through a floating effect.

[0061] In one embodiment, the material of metal substrate 100 is prepared by electroslag remelting and then vacuum arc melting. The material is firstly processed by electroslag remelting, and then further purified through vacuum arc melting, thus facilitating the reduction of the content of the particles.

[0062] The size and the average content of the particles are reasonably controlled based on the wall thickness of the metal substrate 100 of the implantable device. It has been determined from tests that the embodiments can effectively avoid the adverse effects of the particles in the material on the microstructure of the metal substrate 100, thus facilitating the improvement of the plastic deformation capacity of the implantable device to reduce the risk of abnormal fracture of the implantable device.

[0063] Further, the size and the average content of the particles are rationally controlled based on the wall thickness and theoretical over-expansion capacity of the metal substrate 100, thus further optimizing the microstructure of the metal substrate 100, thereby enhancing the plastic deformation capacity of the implantable device.

[0064] Examples are provided hereafter (coronary stents and peripheral vascular stents are set as examples below to further describe the above implantable device, but the protection scope of the embodiments is not limited thereto).

[0065] The particles referred to in the following examples are particles having a size of 1 μ m or more. Samples in the following examples were prepared as follows: materials were ground and polished on an ECO Met 250 semi-automatic polisher manufactured by BRUKER to

obtain sections having shiny mirror surfaces, and then the sections were observed under a scanning electron microscope; or the samples were placed in liquid nitrogen for brittle fracture to obtain sections, and then the sections were observed under a scanning electron microscope at 500 magnifications.

[0066] An expansion test served to assess the influences of the particles on the plastic deformation capacity of the stent. A portion of raw materials were randomly selected and prepared into three tubes or three wires and the like to prepare intravascular stents; the length of the tubes or wires prepared from the selected raw materials should be not less than 1.0 m. These tubes or wires were made into stents for over-expansion test as much as possible under the permission of the process conditions; that is, the stents were expanded until fracture; afterwards, the fracture was observed under an SEM produced by a Japanese Cooperation. If no particles were found on the fracture, it was indicated that the fracture of the sent was not affected by the particles; that is, the plastic deformation capacity of the stent was not seriously deteriorated by the particles in the material.

Example 1

[0067] The raw material was nitrided iron, and the nitrided iron was prepared by electroslag remelting and then vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $15\ mm^2$. The result was as follows: the largest particle size was 5 μm and the average content of particles was 5 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a coronary stent having a wall thickness of 0.040 mm and theoretical over-expansion capacity of 60%.

[0068] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 2

[0069] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 10 μm and the average content of particles was 10 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.2 m) to be prepared into a coronary stent having a wall thickness of 0.053 mm and theoretical over-expansion capacity of 51%.

[0070] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 3

[0071] The raw material was pure iron and prepared by vacuum arc melting. The raw material was placed in liquid nitrogen for brittle fracture to obtain a section having an observed area of 12 mm^2 . The result was as follows: the largest particle size was $10 \, \mu m$ and the average content of particles was $40 \, \text{ppm}$. A portion of the raw material was randomly selected and made into 3 tubes (length was $1.5 \, \text{m}$) to be prepared into a coronary stent having a wall thickness of $0.070 \, \text{mm}$ and theoretical over-expansion capacity of 65%.

[0072] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 4

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[0073] The raw material was a cobalt-chromium alloy and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 15 μ m and the average content of particles was 20 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a coronary stent having a wall thickness of 0.080 mm and theoretical over-expansion capacity of 45%.

[0074] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 5

[0075] The raw material was nitrided iron, and the nitrided iron was prepared by electroslag remelting and then vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $15~\text{mm}^2.$ The result was as follows: the largest particle size was $5~\mu\text{m}$ and the average content of particles was 10 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a coronary stent having a wall thickness of 0.090 mm and theoretical over-expansion capacity of 36%.

[0076] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 6

[0077] The raw material was nitrided iron and prepared by vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 5 μm and the average content of particles was 10 ppm. A portion of the raw material was randomly selected and made into 3 tubes

(length was 1.0 m) to be prepared into a coronary stent having a wall thickness of 0.100 mm and theoretical over-expansion capacity of 25%.

[0078] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 7

[0079] The raw material was a magnesium alloy and prepared by vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 10 μm and the average content of particles was 20 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a coronary stent having a wall thickness of 0.120 mm and theoretical over-expansion capacity of 60%.

[0080] The prepared coronary stent was subjected to an expansion test, and no particles were found on the fracture.

Example 8

[0081] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $10~\mu\text{m}$ and the average content of particles was 25 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.150 mm and theoretical over-expansion capacity of 40%.

[0082] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 9

[0083] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $15~\mu\text{m}$ and the average content of particles was 50~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.180~mm and theoretical over-expansion capacity of 50%.

[0084] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 10

[0085] The raw material was a cobalt-chromium alloy

and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 15 μ m and the average content of particles was 60 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.190 mm and theoretical over-expansion capacity of 45%.

[0086] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 11

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[0087] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $20~\mu\text{m}$ and the average content of particles was 100~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.200~mm and theoretical over-expansion capacity of 65%.

[0088] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 12

[0089] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $10~\mu\text{m}$ and the average content of particles was 30 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.200 mm and theoretical over-expansion capacity of 35%.

[0090] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 13

[0091] The raw material was pure iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~mm^2$. The result was as follows: the largest particle size was $15~\mu m$ and the average content of particles was 80~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.200 mm and theoretical over-expansion capacity of 65%.

[0092] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 14

[0093] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $20~\mu\text{m}$ and the average content of particles was 55~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.230~mm and theoretical over-expansion capacity of 60%.

[0094] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 15

[0095] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $15~\mu\text{m}$ and the average content of particles was 110~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.280~mm and theoretical over-expansion capacity of 50%.

[0096] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 16

[0097] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $18~\mu\text{m}$ and the average content of particles was 40~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.290 mm and theoretical over-expansion capacity of 45%.

[0098] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 17

[0099] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was

as follows: the largest particle size was 10 μm and the average content of particles was 20 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.300 mm and theoretical over-expansion capacity of 25%.

[0100] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 18

[0101] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~mm^2$. The result was as follows: the largest particle size was $15~\mu m$ and the average content of particles was 60~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.300~mm and theoretical over-expansion capacity of 35%.

[0102] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Example 19

[0103] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm^2 . The result was as follows: the largest particle size was $25 \mu m$ and the average content of particles was 220 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.300 mm and theoretical over-expansion capacity of 65%.

[0104] The prepared peripheral vascular stent was subjected to an expansion test, and no particles were found on the fracture.

Comparative Example 1

[0105] The raw material was nitrided iron; and Comparative Example 1 differed from Example 2 in that the average content of the particles was 50 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.2 m) to be prepared into a coronary stent the same as that in Example 2.

[0106] The prepared coronary stent was subjected to an expansion test, and as a result, particles were found on 8 fractures of the coronary stent, as shown in Fig. 3, there were particles in the circle of Fig. 3.

Comparative Example 2

[0107] The raw material was nitrided iron; and Com-

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parative Example 2 differed from Example 2 in that the largest particle size was 20 $\mu m.$ A portion of the raw material was randomly selected and made into 3 tubes (length was 1.2 m) to be prepared into a coronary stent the same as that in Example 2.

[0108] The prepared coronary stent was subjected to an expansion test, and as a result, particles were found on 5 fractures of the coronary stent, as shown in Fig. 4, there were particles in the circle of Fig. 4.

Comparative Example 3

[0109] The raw material was nitrided iron, and the nitrided iron was prepared by electroslag remelting and then vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $15~\text{mm}^2$. The result was as follows: the largest particle size was $5~\mu\text{m}$ and the average content of particles was 25~ppm. A portion of the raw material was randomly selected and made into 3~tubes (length was 1.0~m) to be prepared into a coronary stent having a wall thickness of 0.090~mm and theoretical over-expansion capacity of 36%.

[0110] The prepared coronary stent was subjected to an expansion test, and as a result, particles were found on 6 fractures of the coronary stent.

Comparative Example 4

[0111] The raw material was nitrided iron, and the nitrided iron was prepared by electroslag remelting and then vacuum arc melting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $15~\text{mm}^2.$ The result was as follows: the largest particle size was $20~\mu\text{m}$ and the average content of particles was 10~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a coronary stent having a wall thickness of 0.090~mm and theoretical over-expansion capacity of 36%.

[0112] The prepared coronary stent was subjected to an expansion test, and as a result, particles were found on 4 fractures of the coronary stent.

Comparative Example 5

[0113] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $15~\mu\text{m}$ and the average content of particles was 110~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.180~mm and theoretical over-expansion capacity of 50%.

[0114] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles

were found on 8 fractures of the peripheral vascular stent.

Comparative Example 6

[0115] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was 25 μ m and the average content of particles was 50 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.180 mm and theoretical over-expansion capacity of 50%.

[0116] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 8 fractures of the peripheral vascular stent.

Comparative Example 7

[0117] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~mm^2$. The result was as follows: the largest particle size was $10~\mu m$ and the average content of the particles was 55~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.200~mm and theoretical over-expansion capacity of 35%.

[0118] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 7 fractures of the peripheral vascular stent.

Comparative Example 8

[0119] The raw material was nitrided iron and prepared by electroslag remelting. The material was prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm². The result was as follows: the largest particle size was 25 μm and the average content of the particles was 30 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.200 mm and theoretical over-expansion capacity of 35%.

[0120] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 5 fractures of the peripheral vascular stent.

Comparative Example 9

[0121] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm^2 . The result was as follows: the largest particle size was $15 \mu m$ and the

average content of the particles was 120 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.300 mm and theoretical over-expansion capacity of 35%.

[0122] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 10 fractures of the peripheral vascular stent.

Comparative Example 10

[0123] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was $30~\mu\text{m}$ and the average content of the particles was 60~ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0~m) to be prepared into a peripheral vascular stent having a wall thickness of 0.300~mm and theoretical over-expansion capacity of 35%.

[0124] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 8 fractures of the peripheral vascular stent.

Comparative Example 11

[0125] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of 10 mm^2 . The result was as follows: the largest particle size was $15 \mu m$ and the average content of the particles was 230 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.280 mm and theoretical over-expansion capacity of 50%.

[0126] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 8 fractures of the peripheral vascular stent.

Comparative Example 12

[0127] The raw material was nitrided iron and prepared by electroslag remelting. A portion of the raw material was randomly cut, ground and polished to obtain a bright section with an observed area of $10~\text{mm}^2$. The result was as follows: the largest particle size was 30 μm and the average content of the particles was 110 ppm. A portion of the raw material was randomly selected and made into 3 tubes (length was 1.0 m) to be prepared into a peripheral vascular stent having a wall thickness of 0.280 mm and theoretical over-expansion capacity of 50%.

[0128] The prepared peripheral vascular stent was subjected to an expansion test, and as a result, particles were found on 8 fractures of the peripheral vascular stent.
[0129] It can be seen from the above examples and

comparative examples that the level of the particles in the material is controlled based on the different wall thickness of intravascular stents to avoid or reduce the adverse effect of the particles on the plastic deformation capacity of the stent.

[0130] Compared with Comparative Example 1, the particles in Example 2 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 2, the particles in Example 2 have a smaller largest particle size and weaker deterioration to the plastic deformation capacity of the stent.

[0131] Compared with Comparative Example 3, the particles in Example 5 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 4, the particles in Example 5 have a smaller largest particle size, and weaker deterioration to the plastic deformation capacity of the stent.

[0132] Compared with Comparative Example 5, the particles in Example 9 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 6, the particles in Example 9 have a smaller largest particle size, and weaker deterioration to the plastic deformation capacity of the stent.

[0133] Compared with Comparative Example 7, the particles in Example 12 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 8, the particles in Example 12 have a smaller largest particle size, and weaker deterioration to the plastic deformation capacity of the stent.

[0134] Compared with Comparative Example 9, the particles in Example 18 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 10, the particles in Example 18 have a smaller largest particle size, and weaker deterioration to the plastic deformation capacity of the stent.

[0135] Compared with Comparative Example 11, the particles in Example 15 have a lower average content, small probability of occurrence in key deformation sites, and less adverse effect on the plastic deformation capacity of the stent; compared with Comparative Example 12, the particles in Example 15 have a smaller largest particle size, and weaker deterioration to the plastic deformation capacity of the stent.

[0136] The features of the above examples may be combined in any combination and are non-limiting. In order to simplify the description of the embodiments, all possible combinations of the features in the above examples are not described one by one. Moreover, the com-

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binations of these features should fall within the scope of the embodiments as long as there is no discrepancy among the combinations thereof.

[0137] The examples set forth above merely represent several embodiments, and are described in greater detail but are not to be construed as limiting. It should be indicated that a person of ordinary skill in the art can further make numerous variations and improvements without departing from the spirit of the embodiments. Moreover, these variations and improvements fall within the protection scope of the embodiments.

Claims

1. An implantable device, comprising: a metal substrate, the metal substrate comprising particles having a size of 1 μ m or more, wherein:

if a wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m and an average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μ m and the average content of the particles is less than or equal to 100 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m and the average content of the particles is less than or equal to 220 ppm.

The implantable device according to claim 1, wherein,

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m and the average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μ m and the average content of the particles is less than or equal to 100 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μ m and the average content of the particles is less than or equal to 220 ppm.

The implantable device according to claim 1, wherein

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m and the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μm and the average content of the particles is less than or equal to 50 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μ m and the average content of the particles is less than or equal to 110 ppm.

 The implantable device according to claim 1, wherein,

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 40 ppm;

if the wall thickness of the metal substrate is larger than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is smaller than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 50 ppm; if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 100 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m; and if the theoretical

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over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 110 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 220 ppm.

The implantable device according to claim 1, wherein,

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is greater than or equal to 25 ppm:

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 50 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 $\mu m;$ and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 25 μ m; and if the theoretical

over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

The implantable device according to claim 1, wherein.

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 10 ppm;

if the wall thickness of the metal substrate is greater than or equal to 0.04 mm and less than or equal to 0.12 mm, the largest size of the particles is less than or equal to 10 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 20 ppm;

if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 25 ppm; if the wall thickness of the metal substrate is greater than 0.12 mm and less than or equal to 0.2 mm, the largest size of the particles is less than or equal to 15 μm ; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 50 ppm;

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μm ; and if the theoretical over-expansion capacity of the metal substrate ranges from 25% to 45%, the average content of the particles is less than or equal to 55 ppm; and

if the wall thickness of the metal substrate is greater than 0.2 mm and less than or equal to 0.3 mm, the largest size of the particles is less than or equal to 20 μ m; and if the theoretical over-expansion capacity of the metal substrate is greater than 45%, the average content of the particles is less than or equal to 110 ppm.

7. The implantable device according to claim 1, wherein the material of the metal substrate is selected from one of: nitrided iron, pure iron, cobalt-chromium alloys, and magnesium alloys.

- **8.** The implantable device according to claim 1, wherein the implantable device is an intravascular stent, a biliary stent, an esophageal stent, or a urethral stent.
- **9.** The implantable device according to claim 8, wherein the intravascular stent is a coronary stent or a peripheral vascular stent.
- **10.** The implantable device according to claim 1, wherein the material of the metal substrate is prepared by electroslag remelting and then vacuum arc melting.

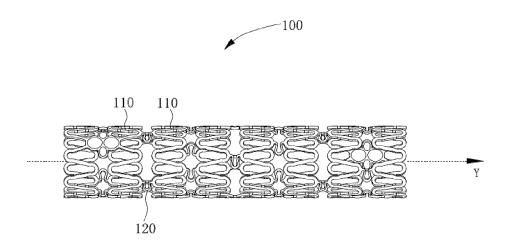


Fig. 1

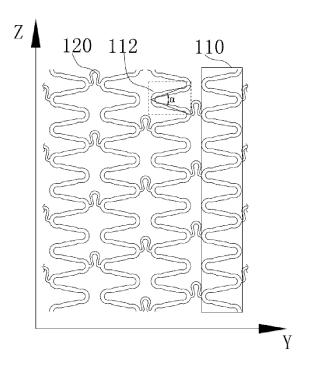


Fig. 2

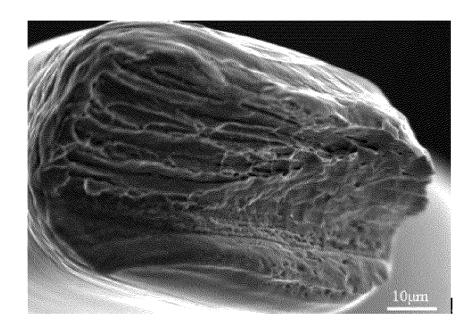


Fig. 3

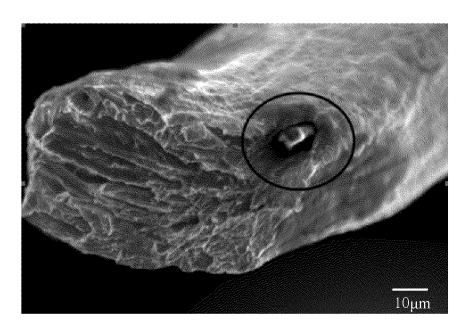


Fig. 4

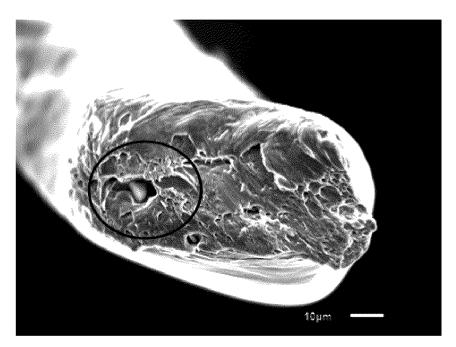


Fig. 5

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INTERNATIONAL SEARCH REPORT

International application No.

PCT/CN2019/110986

5	A. CLASSIFICATION OF SUBJECT MATTER			
	A61L 27/04(2006.01)i; A61F 2/82(2013.01)i			
	According to International Patent Classification (IPC) or to both national classification and IPC			
	B. FIELDS SEARCHED			
10	Minimum documentation searched (classification system followed by classification symbols)			
	A61f2,A61L31,A61L27			
	Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched			
15	Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)			
	EPTXT; VEN; USTXT; WOTXT; CNABS; CNTXT: 支架, 夹杂物, 颗粒, 金属基体, 含量, 尺寸, 断裂, 柔韧, metal, size, content, particles, grains, implant, grains, stent			
	C. DOCUMENTS CONSIDERED TO BE RELEVANT			
20	Category*	Citation of document, with indication, where	appropriate, of the relevant passages	Relevant to claim No.
	X	WO 2017204803 A1 (Q3 MEDICAL DEVICES LTD. et al.) 30 November 2017 (2017-11-30) description, paragraphs 17, 41, 75, and 76		1-10
	Α	CN 109310493 A (FORT WAYNE METALS RES PROD.) 05 February 2019 (2019-02-05) entire document		1-10
25	A	CN 103371876 A (LIFETECH SCIENTIFIC (SHE) (2013-10-30) entire document	VZHEN) CO., LTD.) 30 October 2013	1-10
20	A	CN 106367714 A (LIFETECH SCIENTIFIC (SHE) (2017-02-01) entire document	√ZHEN) CO., LTD.) 01 February 2017	1-10
30	A	WO 2017184750 A1 (FORT WAYNE METALS RES PROD. et al.) 26 October 2017 (2017-10-26) entire document		1-10
35	A	US 2003083731 A1 (ABBOTT CARDIOVASCUL. (2003-05-01) entire document	AR SYSTEMS INC. et al.) 01 May 2003	1-10
	Further documents are listed in the continuation of Box C. See patent family annex.			
40	filing date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means		"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art	
45	"P" document published prior to the international filing date but later than the priority date claimed "&" document member of the same		"&" document member of the same patent far	mily
	Date of the actual completion of the international search		Date of mailing of the international search report	
	13 January 2020		06 February 2020	
50	Name and mailing address of the ISA/CN China National Intellectual Property Administration (ISA/		Authorized officer	
	CN)	ucheng Road, Jimenqiao Haidian District, Beijing		
55		(86-10)62019451 /210 (second sheet) (January 2015)	Telephone No.	

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INTERNATIONAL SEARCH REPORT International application No. Information on patent family members PCT/CN2019/110986 Publication date Publication date Patent document Patent family member(s) (day/month/year) (day/month/year) cited in search report WO 2017204803 **A**1 30 November 2017 JP 2019516468 A 20 June 2019 EP 3463205 10 April 2019 **A**1 CN 109688982 26 April 2019 A 109310493 WO 2017184750CN Α 05 February 2019 A1 26 October 2017 27 February 2019 ΕP 3445281 A1JP 201951813527 June 2019 A EP 3445281 18 December 2019 A4 CN 103371876 A 30 October 2013 US 9878072 B2 30 January 2018 ΑU 2013247205 A127 November 2014 ΑU 2013247205 B2 08 February 2018 EP 2837359 **A**1 18 February 2015 WO 2013152728 A117 October 2013 US 2015151027 A104 June 2015 EP 2837359 A4 09 December 2015 CN 103371876 В 20 January 2016 CN 106367714 01 February 2017 EP 3327163 30 May 2018 A A120 March 2019 EP 3327163 A4 2018221536 09 August 2018 US A1107923010 17 April 2018 CN Α 2017016367 02 February 2017 WO A1WO 2017184750 **A**1 26 October 2017 EP 3445281 A127 February 2019 JP 2019518135 Α 27 June 2019 CN 109310493 Α 05 February 2019 EP 3445281 A4 18 December 2019 US 2003083731 A101 May 2003 US 8211164 B203 July 2012 US 2007255387 A101 November 2007 US 8562664 B222 October 2013 US 8579960 B212 November 2013 US 2012265291**A**1 18 October 2012 US 8419785 B216 April 2013 US 2008015683**A**1 17 January 2008 WO 03035130 **A**1 01 May 2003

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